EAST Search History

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L1	89412	(thin adj2 film adj2 transistor$1) or tft$1	US-PGPUB; USPAT; USOCR; EPO; JPO; IBM_TDB	OR	ON	2006/04/02 15:36
L2	859254	gate$1	US-PGPUB; USPAT; USOCR; EPO; JPO; IBM_TDB	OR	ON	2006/04/02 15:36
L3	109827	gate adj2 (insulat$3 or dielectric or oxide)	US-PGPUB; USPAT; USOCR; EPO; JPO; IBM_TDB	OR	ON	2006/04/02 15:37
L4	1455959	semiconduct$3 or silicon	US-PGPUB; USPAT; USOCR; EPO; JPO; IBM_TDB	OR	ON	2006/04/02 15:37
L5	141648	polysilicon or poly-si or polysi or polycrystalline adj (si or silicon)	US-PGPUB; USPAT; USOCR; EPO; JPO; IBM_TDB	OR	ON	2006/04/02 15:37
L6	238798	source same drain	US-PGPUB; USPAT; USOCR; EPO; JPO; IBM_TDB	OR	ON	2006/04/02 15:37
L7	109827	2 same 3	US-PGPUB; USPAT; USOCR; EPO; JPO; IBM_TDB	OR	ON	2006/04/02 15:38
L8	170903	intrinsic or undoped or un-doped	US-PGPUB; USPAT; USOCR; EPO; JPO; IBM_TDB	OR	ON	2006/04/02 15:38
L9	9551	8 same 5	US-PGPUB; USPAT; USOCR; EPO; JPO; IBM_TDB	OR	ON	2006/04/02 15:40

L10	81868	6 and 7		US-PGPUB; USPAT; USOCR; EPO; JPO; IBM_TDB	OR	ON	2006/04/02 15:39
L11	15888	1 and 4 and 5		US-PGPUB; USPAT; USOCR; EPO; JPO; IBM_TDB	OR	ON	2006/04/02 15:40
L12	788	9 and 10 and 11		US-PGPUB; USPAT; USOCR; EPO; JPO; IBM_TDB	OR	ON	2006/04/02 15:40
L13	2641	8 same 1		US-PGPUB; USPAT; USOCR; EPO; JPO; IBM_TDB	OR	ON	2006/04/02 15:40
L14	13135	8 same 2		US-PGPUB; USPAT; USOCR; EPO; JPO; IBM_TDB	OR	ON	2006/04/02 15:40
L15	586	12 and 14		US-PGPUB; USPAT; USOCR; EPO; JPO; IBM_TDB	OR	ON	2006/04/02 15:41